

PDTA114EU

50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

19 February 2024

Product data sheet

1. General description

PNP Resistor-Equipped Transistor (RET) in a small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

NPN complement: PDTC114EU

2. Features and benefits

- 100 mA output current capability
- · Built-in bias resistors
- · Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

3. Applications

- · Digital application in automotive and industrial segments
- Cost-saving alternative for BC847 series in digital applications
- · Controlling IC inputs
- Switching loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	-50	V
Io	output current			-	-	-100	mA
R1	bias resistor 1 (input)		[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	

[1] See "Section 11: Test information" for resistor calculation and test conditions.



50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)	□ 3	
2	GND	ground (emitter)		R ₁ O
3	0	output (collector)	SC-70 (SOT323)	R2 GND sym003

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PDTA114EU	SC-70	plastic, surface-mounted package; 3 leads; 1.3 mm pitch; 2 mm x 1.25 mm x 0.95 mm body	SOT323

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PDTA114EU	%03

^{[1] % =} placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

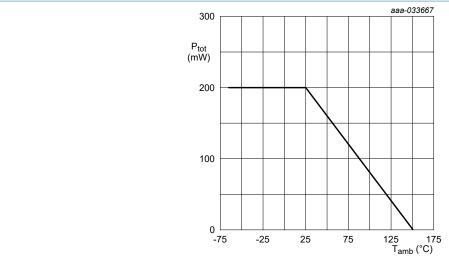
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	-50	V
V _{CEO}	collector-emitter voltage	open base		-	-50	V
V _{EBO}	emitter-base voltage	open collector		-	-10	V
VI	input voltage			-40	10	V
Io	output current			-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

 $^{[1] \}quad \text{Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 } \mu\text{m copper, tin-plated and standard footprint.}$

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FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint

Fig. 1. Power derating curve

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
ang a)	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint.

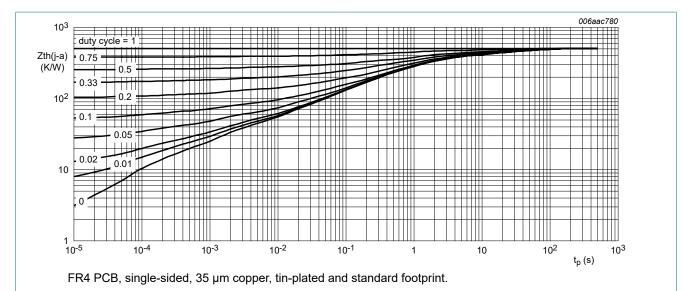


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

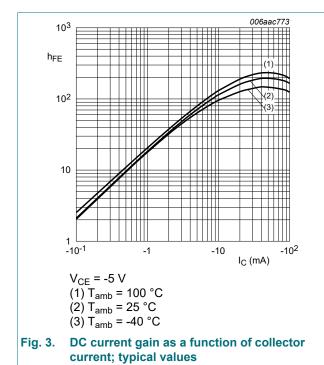
50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

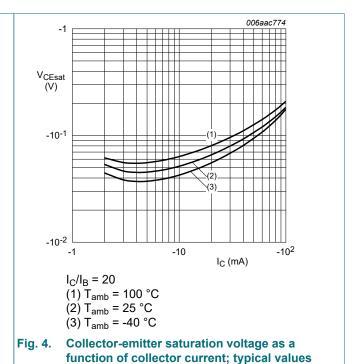
10. Characteristics

Table 7. Characteristics

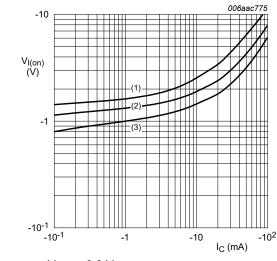
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = -100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		-50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-50	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = -30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	-1	μΑ
	current	V _{CE} = -30 V; I _B = 0 A; T _j = 150 °C		-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-400	μΑ
h _{FE}	DC current gain	V _{CE} = -5 V; I _C = -5 mA; T _{amb} = 25 °C		30	-	-	
V _{CEsat}	collector-emitter saturation voltage	C - , D , and		-	-	-150	mV
$V_{I(off)}$	off-state input voltage	V_{CE} = -5 V; I_{C} = -100 μ A; T_{amb} = 25 °C		-	-1.1	-0.8	V
V _{I(on)}	on-state input voltage	V_{CE} = -0.3 V; I_{C} = -10 mA; T_{amb} = 25 °C		-2.5	-1.8	-	V
R1	bias resistor 1 (input)		[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	8.0	1	1.2	
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; = 1 MHz; T _{amb} = 25 °C		-	-	3	pF
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C	[2]	-	180	-	MHz

- [1] See "Section 11: Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor.



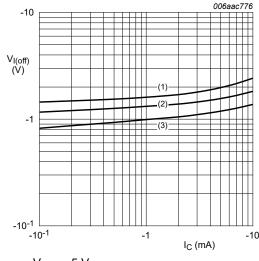


50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω



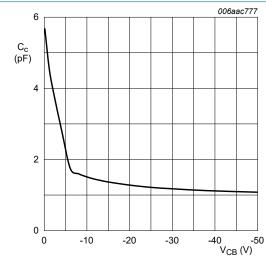
V_{CE} = -0.3 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C





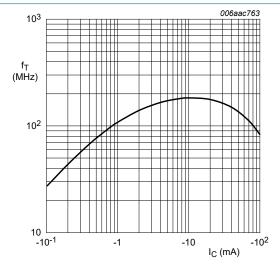
V_{CE} = -5 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

Off-state input voltage as a function of collector current; typical values



 $f = 1 MHz; T_{amb} = 25 °C$

Fig. 7. Collector capacitance as a function of collectorbase voltage; typical values



Transition frequency as a function of collector Fig. 8. current; typical values of built-in transistor

50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

11. Test information

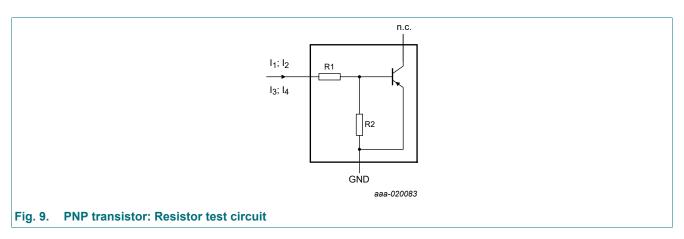
Resistor calculation

· Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$

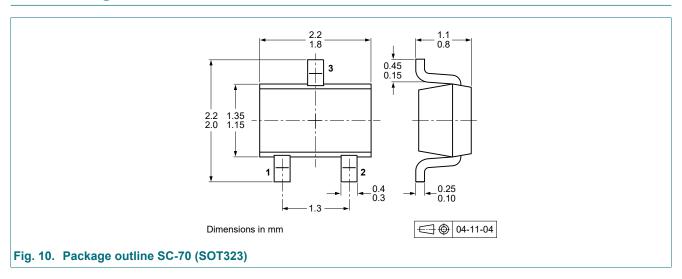


Resistor test conditions

Table 8. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I ₁	l ₂	l ₃	14
PDTA114EU	10	10	-350 μΑ	-450 μA	350 μΑ	450 µA

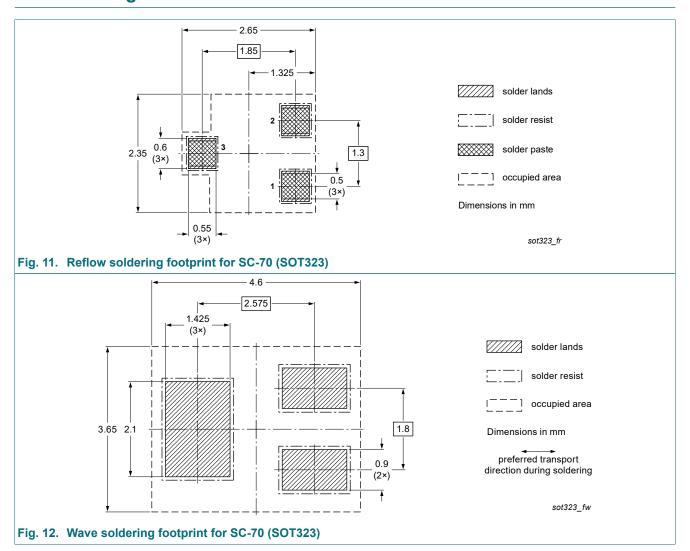
12. Package outline



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13. Soldering



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14. Revision history

Table 9. Revision history

Table 5. Revision history								
Data sheet ID	Release date		Change notice	Supersedes				
PDTA114EU v.13	20240219	Product data sheet	-	PDTA114EU v.12				
Modification:	Pinning: Grap	hic symbol adjusted						
PDTA114EU v.12	20230401	Product data sheet	-	PDTA114E_SER v.11				
PDTA114EU v.11	20230207	Product data sheet	-	PDTA114E_SER v.10				
PDTA114E_SER v.10	20111221	Product data sheet	-	PDTA114E_SER v.9				
PDTA114E_SER v.9	20111122	Product data sheet	-	PDTA114E_SERIES v.8				
PDTA114E_SERIES v.8	20040802	Product specification	-	PDTA114E_SERIES v.7				
PDTA114E_SERIES v.7	20030410	Product specification	-	-				

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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